# Micropower Voltage Reference Diodes

The LM285/LM385 series are micropower two-terminal bandgap voltage regulator diodes. Designed to operate over a wide current range of 10  $\mu$ A to 20 mA, these devices feature exceptionally low dynamic impedance, low noise and stable operation over time and temperature. Tight voltage tolerances are achieved by on-chip trimming. The large dynamic operating range enables these devices to be used in applications with widely varying supplies with excellent regulation. Extremely low operating current make these devices ideal for micropower circuitry like portable instrumentation, regulators and other analog circuitry where extended battery life is required.

The LM285/LM385 series are packaged in a low cost TO-226 plastic case and are available in two voltage versions of 1.235 V and 2.500 V as denoted by the device suffix (see Ordering Information table). The LM285 is specified over a  $-40^{\circ}$ C to  $+85^{\circ}$ C temperature range while the LM385 is rated from  $0^{\circ}$ C to  $+70^{\circ}$ C.

The LM385 is also available in a surface mount plastic package in voltages of  $1.235\ V$  and  $2.500\ V$ .

#### **Features**

- Operating Current from 10 µA to 20 mA
- 1.0%, 1.5%, 2.0% and 3.0% Initial Tolerance Grades
- Low Temperature Coefficient
- 1.0 Ω Dynamic Impedance
- Surface Mount Package Available
- Pb-Free Packages are Available

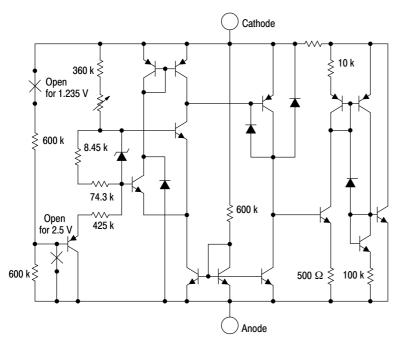


Figure 1. Representative Schematic Diagram



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### MARKING DIAGRAMS

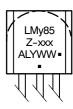


SOIC-8 D SUFFIX CASE 751





TO-92 (TO-226) Z SUFFIX CASE 29



xxx = 1.2 or 2.5

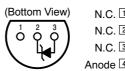
y = 2 or 3z = 1 or 2

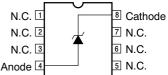
A = Assembly Location

L = Wafer Lot Y = Year

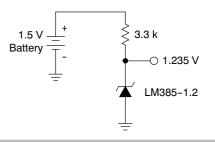
W, WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)





#### **Standard Application**



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

# MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Current	I <sub>R</sub>	30	mA
Forward Current	I <sub>F</sub>	10	mA
Operating Ambient Temperature Range  LM285  LM385	T <sub>A</sub>	-40 to +85 0 to +70	°C
Operating Junction Temperature	$T_J$	+150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to + 150	°C
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM) Charged Device Model (CDM)	ESD	4000 400 2000	٧

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, unless otherwise noted)

		L	_M285-1.:	2	LM385-	-1.2/LM38	5B-1.2	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
$\label{eq:Reverse Breakdown Voltage (I_{Rmin} \le I_R \le 20 \text{ mA})} \\ LM285-1.2/LM385B-1.2 \\ T_A = T_{low} \text{ to } T_{high} \text{ (Note 1)} \\ LM385-1.2 \\ T_A = T_{low} \text{ to } T_{high} \text{ (Note 1)} \\$	V <sub>(BR)R</sub>	1.223 1.200 - -	1.235 - - -	1.247 1.270 - -	1.223 1.210 1.205 1.192	1.235 - 1.235 -	1.247 1.260 1.260 1.273	V
Minimum Operating Current $T_A = 25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 1)	I <sub>Rmin</sub>	-	8.0	10 20	-	8.0 -	15 20	μΑ
Reverse Breakdown Voltage Change with Current $I_{Rmin} \leq I_R \leq 1.0$ mA, $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 1) $1.0$ mA $\leq I_R \leq 20$ mA, $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 1)	ΔV <sub>(BR)R</sub>	- - - -	- - - -	1.0 1.5 10 20	- - - -	- - - -	1.0 1.5 20 25	mV
Reverse Dynamic Impedance $I_R = 100 \mu A, T_A = +25^{\circ}C$	Z	-	0.6	-	-	0.6	-	Ω
Average Temperature Coefficient 10 $\mu$ A $\leq$ I <sub>R</sub> $\leq$ 20 mA, T <sub>A</sub> = T <sub>low</sub> to T <sub>high</sub> (Note 1)	$\Delta V_{(BR)}/\Delta T$	-	80	-	-	80	-	ppm/°C
Wideband Noise (RMS) $I_R = 100 \ \mu\text{A}, \ 10 \ \text{Hz} \le f \le 10 \ \text{kHz}$	n	-	60	-	-	60	-	μV
Long Term Stability $I_R = 100 \ \mu\text{A}, \ T_A = +25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$	S	-	20	-	-	20	-	ppm/kHR
$\label{eq:Reverse Breakdown Voltage (I_{Rmin} \le I_R \le 20 \text{ mA})} \\ LM285-2.5/LM385B-2.5 \\ T_A = T_{low} \text{ to } T_{high} \text{ (Note 1)} \\ LM385-2.5 \\ T_A = T_{low} \text{ to } T_{high} \text{ (Note 1)} \\$	V <sub>(BR)R</sub>	2.462 2.415 - -	2.5 - - -	2.538 2.585 - -	2.462 2.436 2.425 2.400	2.5 - 2.5 -	2.538 2.564 2.575 2.600	V
Minimum Operating Current $T_A = 25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 1)	I <sub>Rmin</sub>	-	13 -	20 30	-	13 -	20 30	μΑ

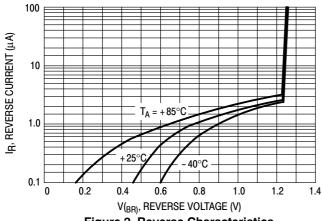
 $<sup>\</sup>begin{array}{lll} T_{low} & = -40^{\circ} C \text{ for LM285-1.2, LM285-2.5} \\ T_{high} & = +85^{\circ} C \text{ for LM285-1.2, LM285-2.5} \\ T_{low} & = 0^{\circ} C \text{ for LM385-1.2, LM385B-1.2, LM385B-2.5, LM385B-2.5} \\ T_{high} & = +70^{\circ} C \text{ for LM385-1.2, LM385B-1.2, LM385B-2.5, LM385B-2.5} \\ \end{array}$ 

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25$ °C, unless otherwise noted)

		I	_M285-1.:	2	LM385-	-1.2/LM38	35B-1.2	
Characteristic	Symbol	Min	Тур	Max	Min	Тур	Max	Unit
Reverse Breakdown Voltage Change with Current $I_{Rmin} \leq I_R \leq$ 1.0 mA, $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 2) 1.0 mA $\leq I_R \leq$ 20 mA, $T_A = +25^{\circ}C$ $T_A = T_{low}$ to $T_{high}$ (Note 2)	$\Delta V_{(BR)R}$	- - -	- - -	1.0 1.5 10 20	- - -	- - -	2.0 2.5 20 25	mV
Reverse Dynamic Impedance $I_R = 100 \mu A, T_A = +25^{\circ} C$	Z	-	0.6	-	-	0.6	-	Ω
Average Temperature Coefficient 20 $\mu$ A $\leq$ I <sub>R</sub> $\leq$ 20 mA, T <sub>A</sub> = T <sub>low</sub> to T <sub>high</sub> (Note 2)	$\Delta V_{(BR)}/\Delta T$	-	80	-	-	80	-	ppm/°C
Wideband Noise (RMS) $I_R$ = 100 $\mu$ A, 10 Hz $\leq$ f $\leq$ 10 kHz	n	-	120	-	-	120	-	μV
Long Term Stability $I_R = 100~\mu\text{A},~T_A = +25^{\circ}\text{C} \pm 0.1^{\circ}\text{C}$	S	-	20	_	-	20	-	ppm/kHR

<sup>2.</sup>  $T_{low} = -40^{\circ}\text{C}$  for LM285–1.2, LM285–2.5  $T_{high} = +85^{\circ}\text{C}$  for LM285–1.2, LM285–2.5  $T_{low} = 0^{\circ}\text{C}$  for LM385–1.2, LM385B–1.2, LM385–2.5, LM385B–2.5  $T_{high} = +70^{\circ}\text{C}$  for LM385–1.2, LM385B–1.2, LM385–2.5, LM385B–2.5

## TYPICAL PERFORMANCE CURVES FOR LM285-1.2/385-1.2/385B-1.2



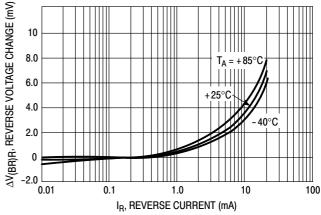
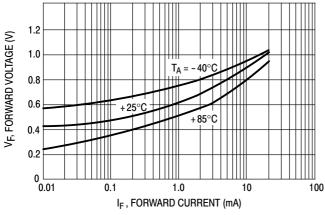
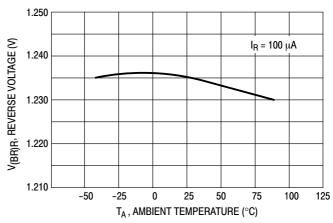


Figure 2. Reverse Characteristics

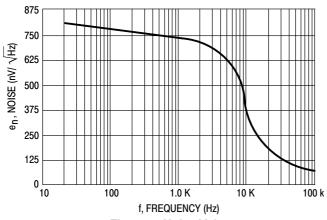
Figure 3. Reverse Characteristics





**Figure 4. Forward Characteristics** 

Figure 5. Temperature Drift



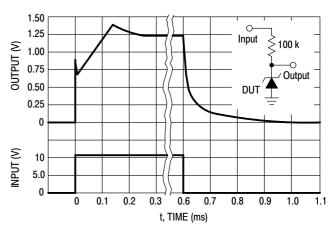


Figure 6. Noise Voltage

Figure 7. Response Time

## TYPICAL PERFORMANCE CURVES FOR LM285-2.5/385-2.5/385B-2.5

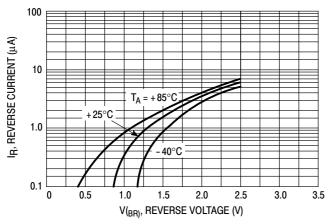
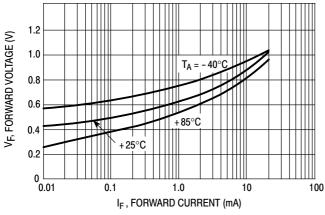


Figure 8. Reverse Characteristics

Figure 9. Reverse Characteristics



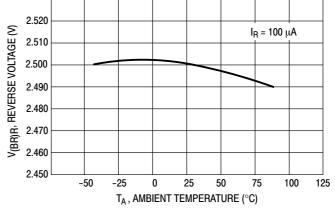
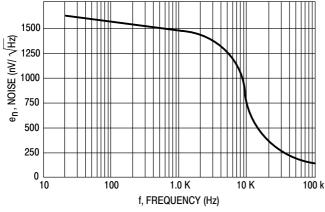


Figure 10. Forward Characteristics

Figure 11. Temperature Drift



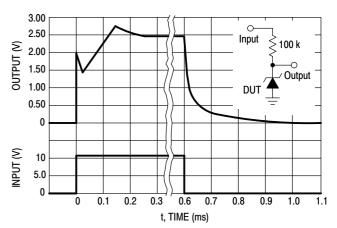


Figure 12. Noise Voltage

Figure 13. Response Time

# **ORDERING INFORMATION**

Device	Operating Temperature Range	Reverse Break-Down Voltage	Package	Shipping <sup>†</sup>
LM285D-1.2			SOIC-8	98 Units / Rail
LM285D-1.2G	]		SOIC-8 (Pb-Free)	98 Units / Rail
LM285D-1.2R2		1.235 V	SOIC-8	2500 / Tape & Reel
LM285D-1.2R2G	]		SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM285D-2.5			SOIC-8	98 Units / Rail
LM285D-2.5G	]	0.500.V	SOIC-8 (Pb-Free)	98 Units / Rail
LM285D-2.5R2		2.500 V	SOIC-8	2500 / Tape & Reel
LM285D-2.5R2G	]		SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM285Z-1.2			TO-92	2000 Units / Bag
LM285Z-1.2G	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.235 V	TO-92 (Pb-Free)	2000 Units / Bag
LM285Z-2.5			TO-92	2000 Units / Bag
LM285Z-2.5G	]	2.500 V	TO-92 (Pb-Free)	2000 Units / Bag
LM285Z-1.2RA			TO-92	2000 / Tape & Reel
LM285Z-1.2RAG	]	1.235 V	TO-92 (Pb-Free)	2000 / Tape & Reel
LM285Z-2.5RA			TO-92	2000 / Tape & Reel
LM285Z-2.5RAG			TO-92 (Pb-Free)	2000 / Tape & Reel
LM285Z-2.5RP		2.500 V	TO-92	2000 Units / Fan-Fold
LM285Z-2.5RPG			TO-92 (Pb-Free)	2000 Units / Fan-Fold
LM385BD-1.2			SOIC-8	98 Units / Rail
LM385BD-1.2G	]	1.005.1/	SOIC-8 (Pb-Free)	98 Units / Rail
LM385BD-1.2R2		1.235 V	SOIC-8	2500 / Tape & Reel
LM385BD-1.2R2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM385BD-2.5			SOIC-8	98 Units / Rail
LM385BD-2.5G	T 000 to .7000	0.500.1/	SOIC-8 (Pb-Free)	98 Units / Rail
LM385BD-2.5R2	$T_A = 0^{\circ}C \text{ to } +70^{\circ}C$	2.500 V	SOIC-8	2500 / Tape & Reel
LM385BD-2.5R2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM385BZ-1.2			TO-92	2000 Units / Bag
LM385BZ-1.2G		1 005 \/	TO-92 (Pb-Free)	2000 Units / Bag
LM385BZ-1.2RA		1.235 V	TO-92	2000 / Tape & Reel
LM385BZ-1.2RAG			TO-92 (Pb-Free)	2000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

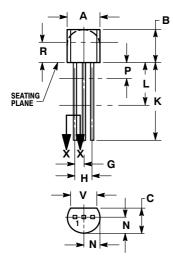
# **ORDERING INFORMATION**

Device	Operating Temperature Range	Reverse Break-Down Voltage	Package	Shipping <sup>†</sup>
LM385BZ-2.5			TO-92	2000 Units / Bag
LM385BZ-2.5G			TO-92 (Pb-Free)	2000 Units / Bag
LM385BZ-2.5RA		2.500 V	TO-92	2000 / Tape & Reel
LM385BZ-2.5RAG			TO-92 (Pb-Free)	2000 / Tape & Reel
LM385D-1.2			SOIC-8	98 Units / Rail
LM385D-1.2G	]	4 005 \	SOIC-8 (Pb-Free)	98 Units / Rail
LM385D-1.2R2		1.235 V	SOIC-8	2500 / Tape & Reel
LM385D-1.2R2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM385D-2.5			SOIC-8	98 Units / Rail
LM385D-2.5G		0.500.\/	SOIC-8 (Pb-Free)	98 Units / Rail
LM385D-2.5R2		2.500 V	SOIC-8	2500 / Tape & Reel
LM385D-2.5R2G	$T_A = 0$ °C to +70°C		SOIC-8 (Pb-Free)	2500 / Tape & Reel
LM385Z-1.2			TO-92	2000 Units / Bag
LM385Z-1.2G			TO-92 (Pb-Free)	2000 Units / Bag
LM385Z-1.2RA			TO-92	2000 / Tape & Reel
LM385Z-1.2RAG		1.235 V	TO-92 (Pb-Free)	2000 / Tape & Reel
LM385Z-1.2RP			TO-92	2000 / Ammo Box
LM385Z-1.2RPG			TO-92 (Pb-Free)	2000 / Ammo Box
LM385Z-2.5			TO-92	2000 Units / Bag
LM385Z-2.5G		0.500.\/	TO-92 (Pb-Free)	2000 Units / Bag
LM385Z-2.5RP		2.500 V	TO-92	2000 / Ammo Box
LM385Z-2.5RPG			TO-92 (Pb-Free)	2000 / Ammo Box

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **PACKAGE DIMENSIONS**

TO-92 (TO-226) CASE 29-11 **ISSUE AM** 

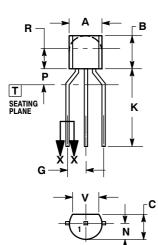


STRAIGHT LEAD **BULK PACK** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	



BENT LEAD **TAPE & REEL** AMMO PACK



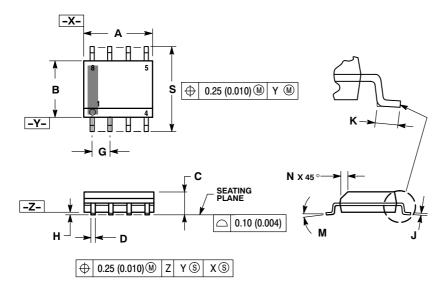
#### NOTES:

- ITES:
  DIMENSIONING AND TOLERANCING PER
  ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  CONTOUR OF PACKAGE BEYOND
  DIMENSION R IS UNCONTROLLED.
  LEAD DIMENSION IS UNCONTROLLED IN P
  AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS					
DIM	MIN	MAX				
Α	4.45	5.20				
В	4.32	5.33				
C	3.18	4.19				
D	0.40	0.54				
G	2.40	2.80				
7	0.39	0.50				
K	12.70					
N	2.04	2.66				
P	1.50	4.00				
R	2.93					
٧	3.43					

#### PACKAGE DIMENSIONS

#### SOIC-8 NB CASE 751-07 **ISSUE AJ**

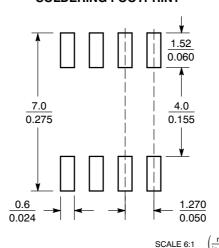


#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	1.27 BSC		0 BSC
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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